NSN 5961-00-147-7444

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Inclosure Material: Metal **Overall Length:** 1.253 inches **Function For Which Designed:** Zener diode **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.423 inches and 0.438 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 110.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 82.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 10.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius case **Precious Material And Location:** Or silver terminal finish option gold **Precious Material:** Gold or silver **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:**

Shelf Life:

Specification Data:

1 threaded stud and 1 tab, solder lug

81349-mil-s-19500/124 government specification

N/a

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Demilitarization:

No

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